

Ultra low capacitance single rail-to-rail ESD protectionRev. 01 — 25 September 2008Product data

Product data sheet

1. Product profile

1.1 General description

Ultra low capacitance single rail-to-rail ElectroStatic Discharge (ESD) protection device in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package designed to protect one Hi-Speed data line or high-frequency signal line from the damage caused by ESD and other transients.

PRTR5V0U1T incorporates one ultra low capacitance rail-to-rail protection channel as well as an additional ESD protection diode to ensure signal line protection even if no supply voltage is available.

1.2 Features

- ESD protection of one Hi-Speed data line or high-frequency signal line
- Ultra low input/output to ground capacitance: C_(I/O-GND) = 1 pF
- ESD protection up to 8 kV
- IEC 61000-4-2, level 4 (ESD)
- Very low clamping voltage due to an integrated additional ESD protection diode
- Very low reverse current
- Small SMD plastic package

1.3 Applications

- USB interfaces (2.0)
- Digital Video Interface (DVI) / High Definition Multimedia Interface (HDMI) interfaces
- Mobile and cordless phones
- Personal Digital Assistants (PDA)
- Digital cameras
- Wide Area Network (WAN) / Local Area Network (LAN) systems
- PCs, notebooks, printers and other PC peripherals



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1.4 Quick reference data

Table 1. Quick reference data

 $T_{amb} = 25 \circ C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------|------------------------------------|---|--------------|-----|-----|------|
| Per channe | el | | | | | |
| C _(I/O-GND) | input/output to ground capacitance | $ f = 1 MHz; V_{(I/O-GND)} = 0 V $ | <u>[1]</u> _ | 1 | 1.5 | pF |
| Zener dioc | le | | | | | |
| V _{RWM} | reverse standoff voltage | | - | - | 5.5 | V |
| C _{sup} | supply pin to ground capacitance | f = 1 MHz; V _{CC} = 0 V | [2] _ | 16 | - | pF |

- [1] Measured from pin 1 to ground.
- [2] Measured from pin 2 to ground.

2. Pinning information

| Table | 2. Pinnin | g | | |
|-------|-----------------|----------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | I/O | input/output | — - | _ |
| 2 | V _{CC} | supply voltage | | 3 |
| 3 | GND | ground | | |

3. Ordering information

| Table 3. Orderin | g informatio | 1 | |
|------------------|--------------|--|---------|
| Type number | Package | | |
| | Name | Description | Version |
| PRTR5V0U1T | - | plastic surface-mounted package; 3 leads | SOT23 |

4. Marking

| Table 4. Marking codes | |
|------------------------------|-----------------------------|
| Type number | Marking code ^[1] |
| PRTR5V0U1T | ZN* |
| [1] * = -: made in Hong Kong | |

- * = p: made in Hong Kong* = t: made in Malaysia
- * = W: made in China

2 006aab111

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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------|------------|-----|------|------|
| Per device | | | | | |
| T _{amb} | ambient temperature | | -40 | +85 | °C |
| T _{stg} | storage temperature | | -55 | +125 | °C |

Table 6.ESD maximum ratings

 $T_{amb} = 25 \circ C$ unless otherwise specified.

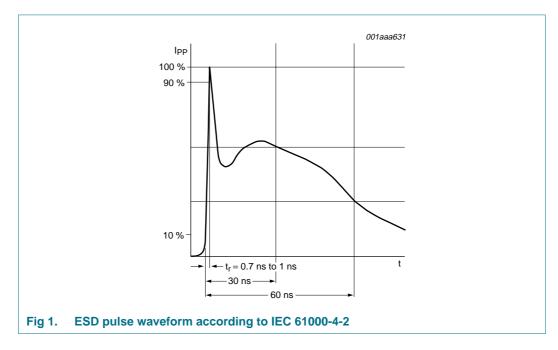
| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------------|--|--------|-----|-----|------|
| Per chan | nel | | | | | |
| V _{ESD} | electrostatic discharge voltage | | [1][2] | | | |
| | | IEC 61000-4-2; level 4 (contact discharge) | | - | 8 | kV |
| | | MIL-STD-883 (human body model) | | - | 10 | kV |

[1] Device stressed with ten non-repetitive ESD pulses.

[2] Measured from pin 1 to 2 or 3.

Table 7. ESD standards compliance

| Standard | Conditions | |
|------------------------------|------------------|--|
| Per diode | | |
| IEC 61000-4-2; level 4 (ESD) | > 8 kV (contact) | |



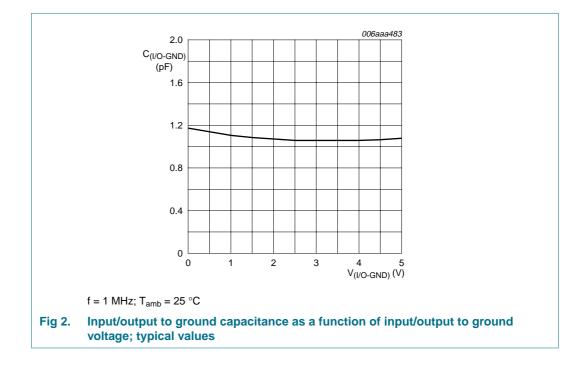
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6. Characteristics

| | Characteristics C unless otherwise specified. | | | | | |
|------------------------|--|-------------------------------------|--------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Per channe |) I | | | | | |
| I _R | reverse current | V _R = 3 V | <u>[1]</u> - | < 1 | 100 | nA |
| C _(I/O-GND) | input/output to ground capacitance | f = 1 MHz; $V_{(I/O-GND)} = 0 V$ | <u>[1]</u> - | 1 | 1.5 | pF |
| V _F | forward voltage | | - | 0.7 | - | V |
| Zener diod | e | | | | | |
| V _{RWM} | reverse standoff voltage | | - | - | 5.5 | V |
| V _{BR} | breakdown voltage | | [2] 6 | - | 9 | V |
| C _{sup} | supply pin to ground capacitance | f = 1 MHz; V _{CC} = 0 V | [2] _ | 16 | - | pF |

[1] Measured from pin 1 to ground.

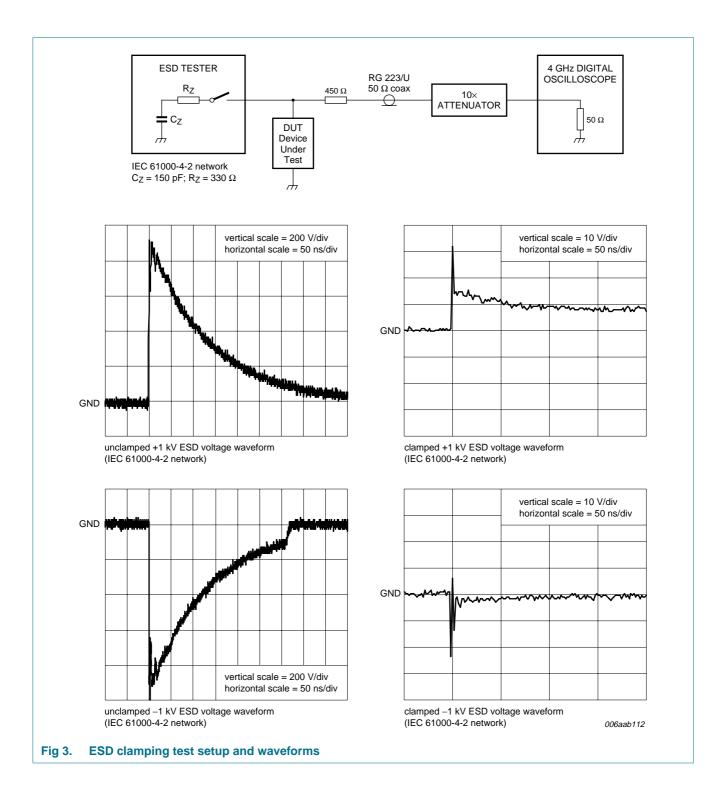
[2] Measured from pin 2 to ground.



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PRTR5V0U1T

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7. Application information

With a capacitance of only 1 pF, the PRTR5V0U1T offers IEC 61000-4-2, level 4 compliant ESD protection.

The PRTR5V0U1T integrates one ultra low capacitance rail-to-rail ESD protection channel and an additional ESD protection diode.

The additional ESD protection diode connected between ground and V_{CC} prevents charging of the supply.

To achieve the maximum ESD protection level, no additional external capacitors are required.

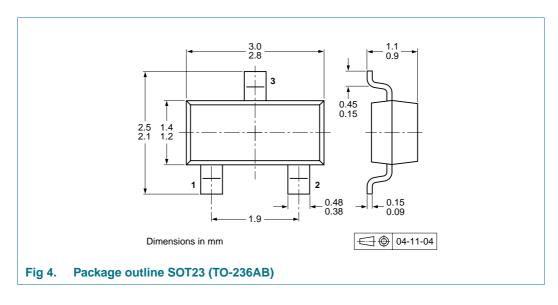
Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the PRTR5V0U1T as close to the input terminal or connector as possible.
- 2. The path length between the PRTR5V0U1T and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

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8. Package outline



9. Packing information

Table 9. Packing methods

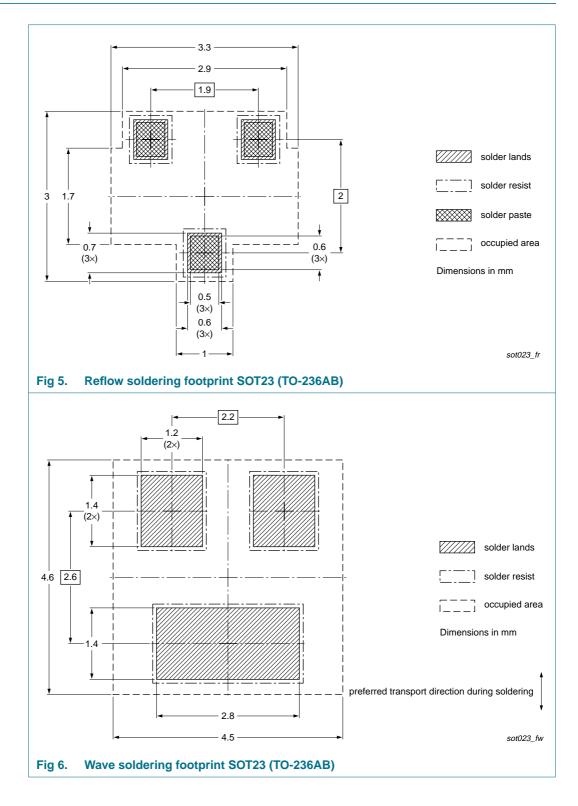
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description | Packing | Packing quantity | |
|-------------|---------|--------------------------------|---------|------------------|--|
| | | | 3000 | 10000 | |
| PRTR5V0U1T | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | -235 | |

[1] For further information and the availability of packing methods, see Section 13.

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10. Soldering



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11. Revision history

| Table 10. Revision hist | able 10. Revision history | | | | | |
|-------------------------|---------------------------|--------------------|---------------|------------|--|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
| PRTR5V0U1T_1 | 20080925 | Product data sheet | - | - | | |

12. Legal information

12.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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